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| Authors | Abstract: Electrical switching behaviour of lead phosphovanadate glasses were studied by determining the current-voltage characteristics. All the investigated glasses exhibit the dependence of threshold voltages on temperature, thickness and composition. Below holding current the I - V characteristics obey Ohms law followed by a negative resistance region where the bulk behaviour dominates and at higher values of current the samples goes to a low resistance state. The studied glasses exhibit memory type switching. It is suggested that the initial switching and channel formation are due to electronic, |
| 0 | while thermal effects dominate in the formation of channels. |
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